Zener Diode

## DZ5J120D0R

# **Panasonic**

### DZ5J120D0R

### Silicon epitaxial planar type

For surge absorption circuit DZ5X120D in SMini5 type package

#### ■ Features

- · Excellent rising characteristics of zener current Iz
- · Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol:05
- Basic Part Number : Dual DZ3X120D (Common anode)

#### ■ Packaging

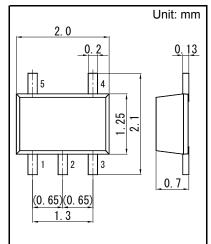
Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)

#### ■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Total power dissipation *1	PT	200	mW
Electrostatic discharge *2	ESD	±10	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

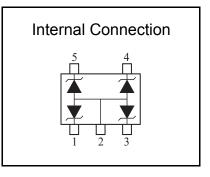
Note) \*1: PT = 200 mW achieved with a printed circuit board. (4Diode total)

\*2: Test method:IEC61000\_4\_2(C = 150 pF,R = 330  $\Omega$ , Contact discharge:10 times)



- 1. Cathode1 4 Cathode3
- 2. Anode1,2,3,4 5. Cathode4
- 3. Cathode2

Panasonic	SMini5-F3-B
JEITA	SC-113CB
Code	SOT-353



#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	11.40		12.60	V
Zener operating resistance	RZ	IZ = 5 mA			30	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			80	Ω
Reverse current	IR	VR = 9 V			0.05	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		8.5		mV/°C

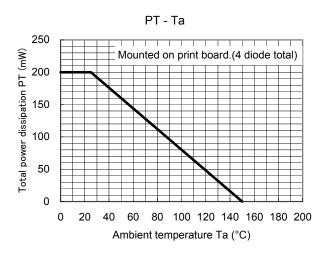
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

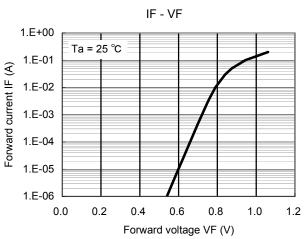
- 2. \*1: The temperature must be controlled 25°C for VZ mesurement.
  - VZ value measured at other temperature must be adjusted to VZ (25°C)
  - \*2: VZ guaranted 20 ms after current flow.
  - \*3: Tj = 25°C to 150°C

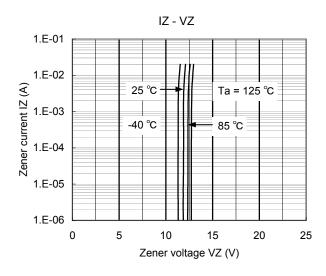
Established : 2011-02-16 Revised : 2013-11-01 **Panasonic** 

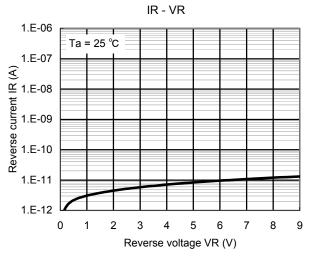
Zener Diode DZ5J120D0R

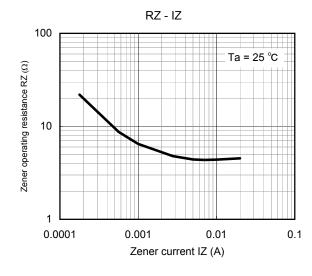
## Technical Data (reference)

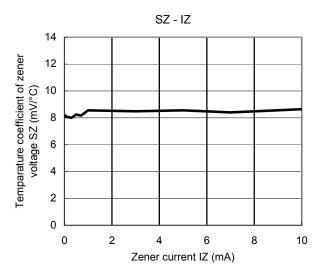












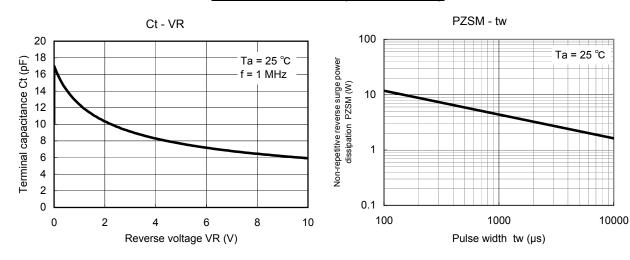
Established: 2011-02-16 Revised: 2013-11-01

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Zener Diode

## DZ5J120D0R

## Technical Data (reference)



Established: 2011-02-16 Revised : 2013-11-01

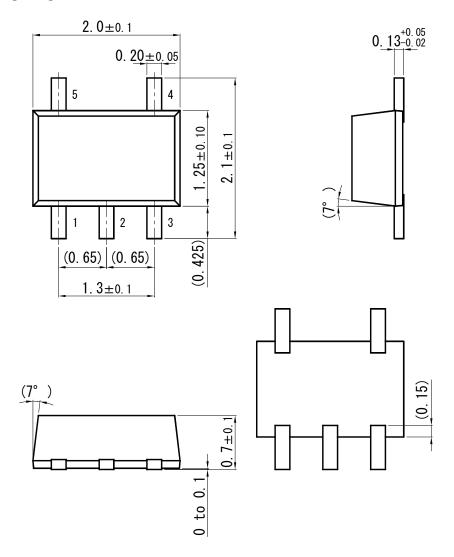
Zener Diode

## DZ5J120D0R

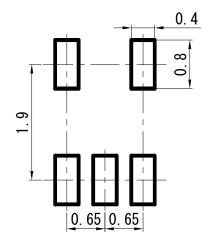
# SMini5-F3-B

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Unit: mm



### ■ Land Pattern (Reference) (Unit: mm)



Established: 2011-02-16 Revised: 2013-11-01

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